

LBC856BWT1G

S-LBC856BWT1G

General Purpose Transistors PNP Silicon

1. FEATURES

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.

2. DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LBC856BWT1G	3B	3000/Tape&Reel

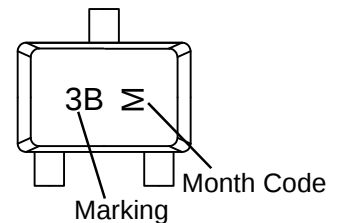
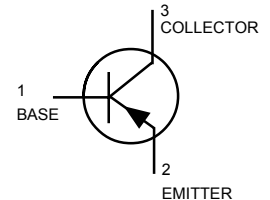
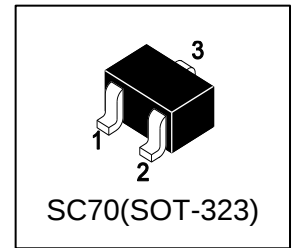
3. MAXIMUM RATINGS(Ta = 25°C)

Parameter	Symbol	Limits	Unit
Collector–Emitter Voltage	VCEO	-65	V
Collector–Base Voltage	VCBO	-80	V
Emitter–Base Voltage	VEBO	-5	V
Collector Current — Continuous	IC	-100	mA

4. THERMAL CHARACTERISTICS

Parameter	Symbol	Limits	Unit
Total Device Dissipation, FR-5 Board (Note 1) @ TA = 25°C	PD	150	mW
Thermal Resistance, Junction–to–Ambient	RθJA	833	°C/W
Junction and Storage temperature	TJ, Tstg	-55~+150	°C

1. FR-5 = 1.0×0.75×0.062 in.



5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

OFF CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Collector–Emitter Breakdown Voltage (IC = -10 mA, IB = 0)	VBR(CEO)	-65	-	-	V
Collector–Emitter Breakdown Voltage (IC = -10 μ A, VEB = 0)	VBR(CES)	-80	-	-	V
Collector–Base Breakdown Voltage (IC = -10 μ A, IE = 0)	VBR(CBO)	-80	-	-	V
Emitter–Base Breakdown Voltage (IE = -1.0 μ A, IC = 0)	VBR(EBO)	-5	-	-	V
Collector Cutoff Current (VCB = -30 V) (VCB = -30 V, TA = 150°C)	ICBO	-	-	-15 -4	nA μ A
Emitter-Base cut-off current (VBE = - 5 V, IC = 0)	IEBO	-	-	-100	nA
Collector-Emitter cutoff Current (VCE= - 65V, IB=0)	ICEO	-	-	-10	μ A

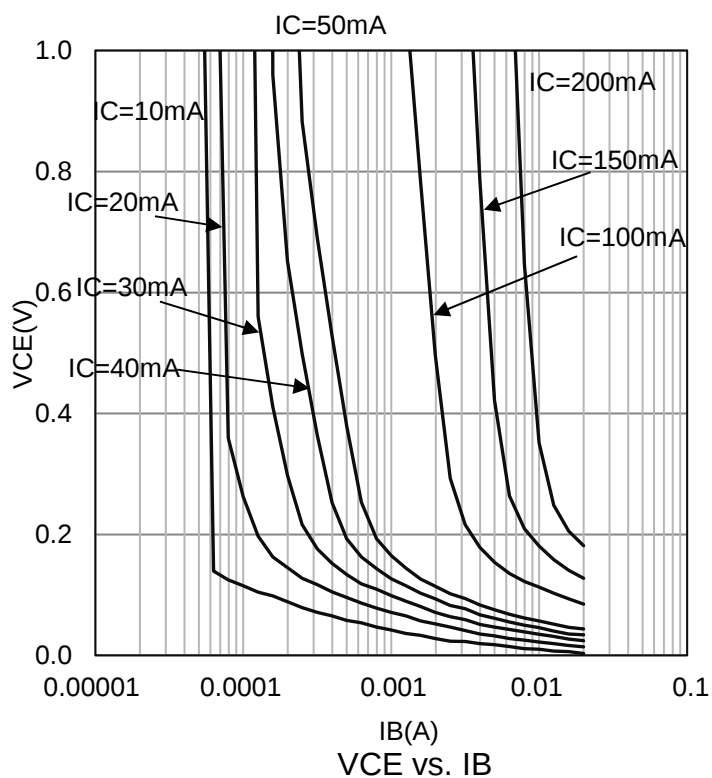
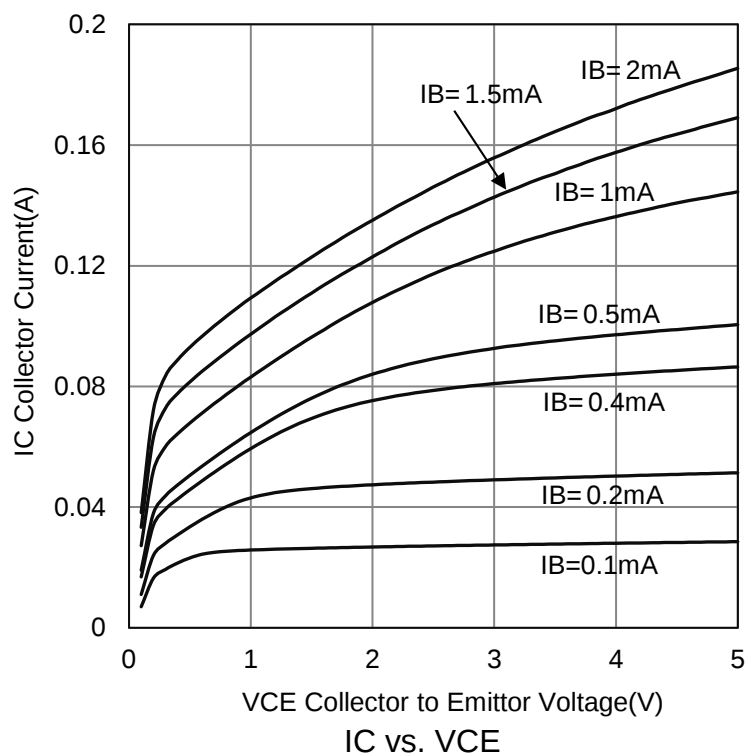
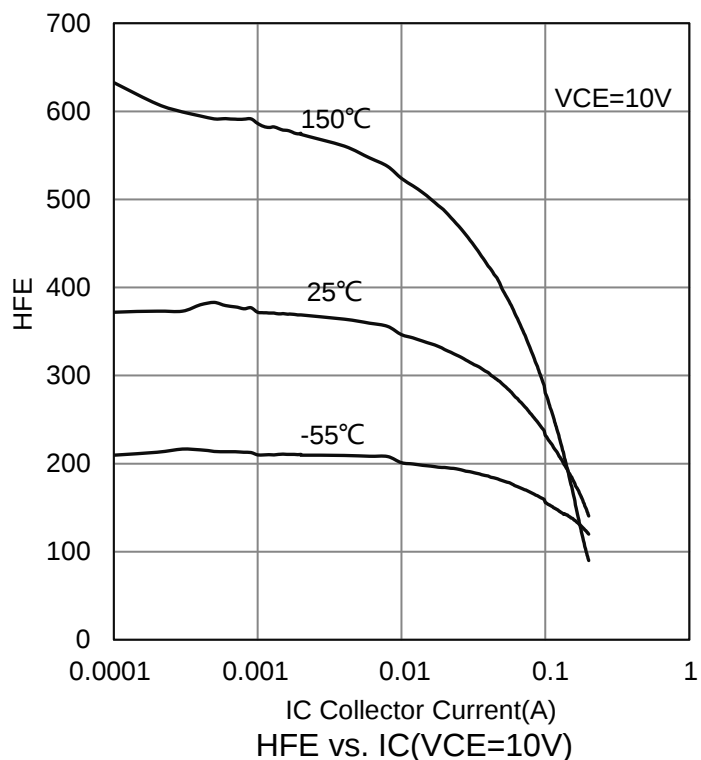
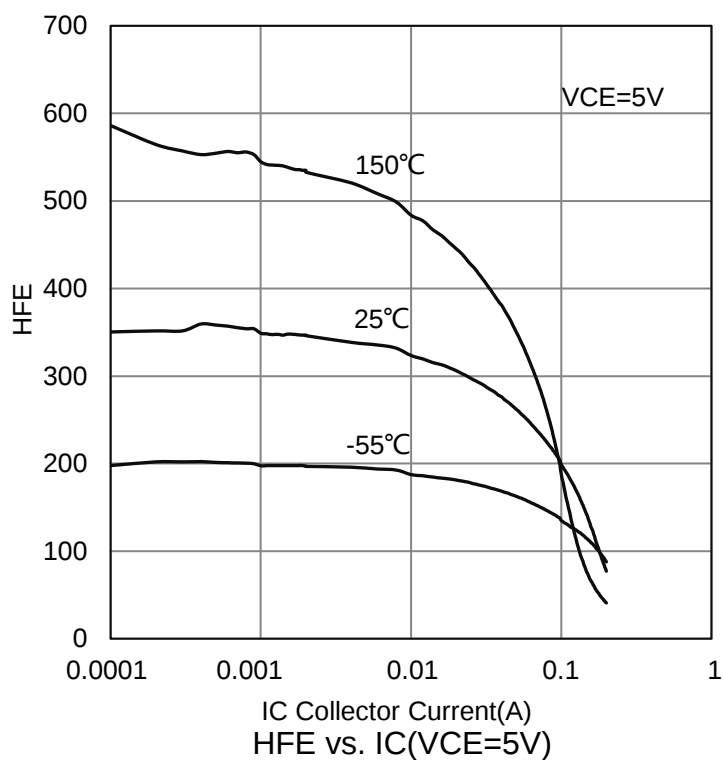
ON CHARACTERISTICS

DC Current Gain (IC = -2.0 mA, VCE = -5.0 V)	HFE	220	290	475	
Collector–Emitter Saturation Voltage (IC = -10 mA, IB = -0.5 mA) (IC = -100 mA, IB = -5.0 mA)	VCE(sat)	-	-	-0.3 -0.65	V
Base–Emitter Saturation Voltage (IC = -10 mA, IB = -0.5 mA) (IC = -100 mA, IB = -5.0 mA)	VBE(sat)	-	-0.7 -0.9	-1 -1.2	V
Base–Emitter on Voltage (IC = -2.0 mA, VCE = -5.0 V) (IC = -10 mA, VCE = -5.0 V)	VBE(on)	-0.6 -	- -	-0.75 -0.82	V

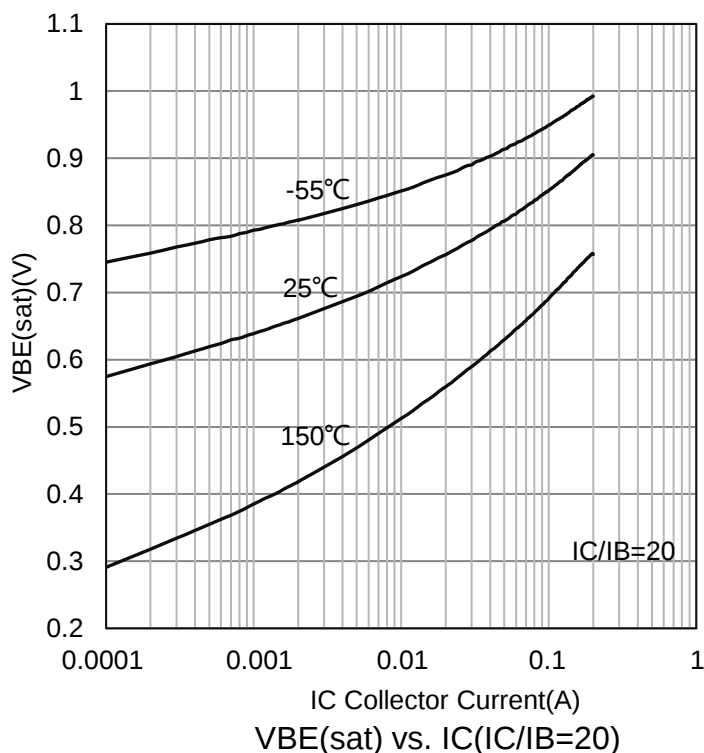
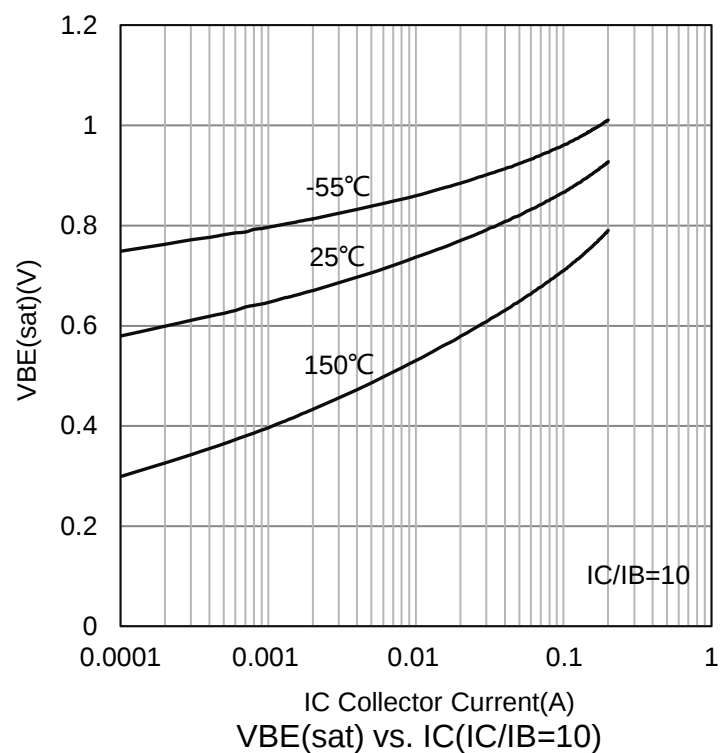
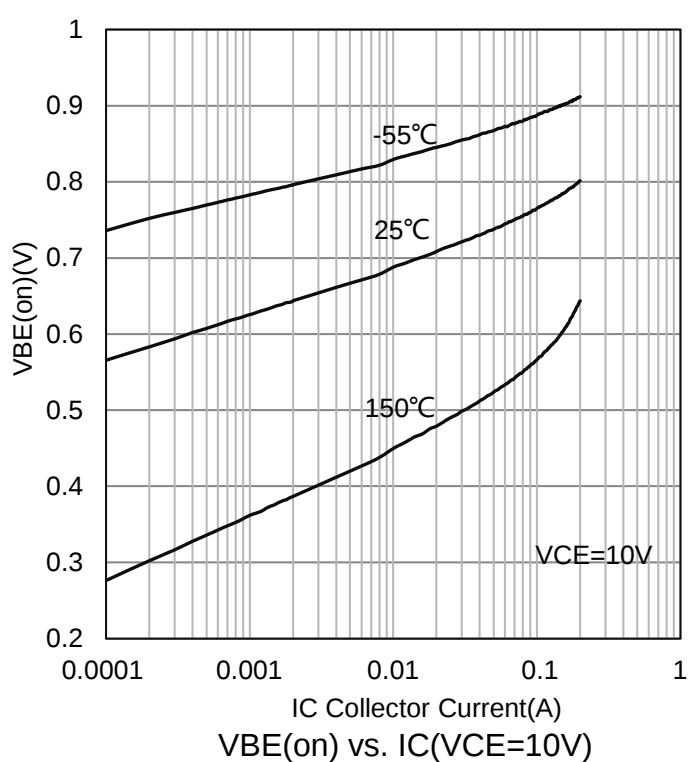
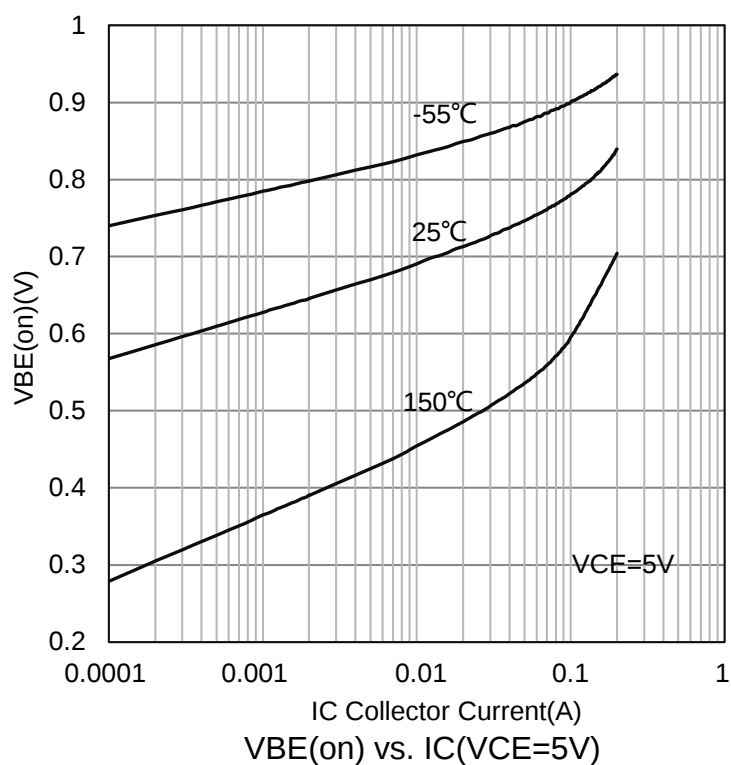
SMALL–SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product (IC = -10 mA, VCE = -5.0 V, f = 100 MHz)	fT	100	-	-	MHz
Output Capacitance (VCB = -10 V, f = 1.0 MHz)	Cobo	-	-	4.5	pF
Noise Figure (IC = -0.2 mA, VCE = -5.0 V, RS = 2.0 k Ω f = 1.0 kHz, BW = 200 Hz)	NF	-	-	10	dB

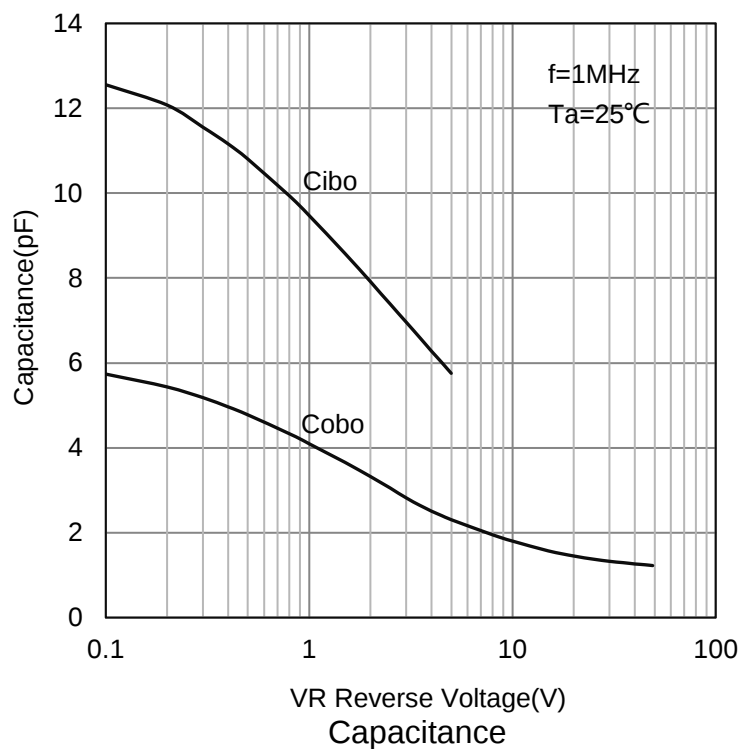
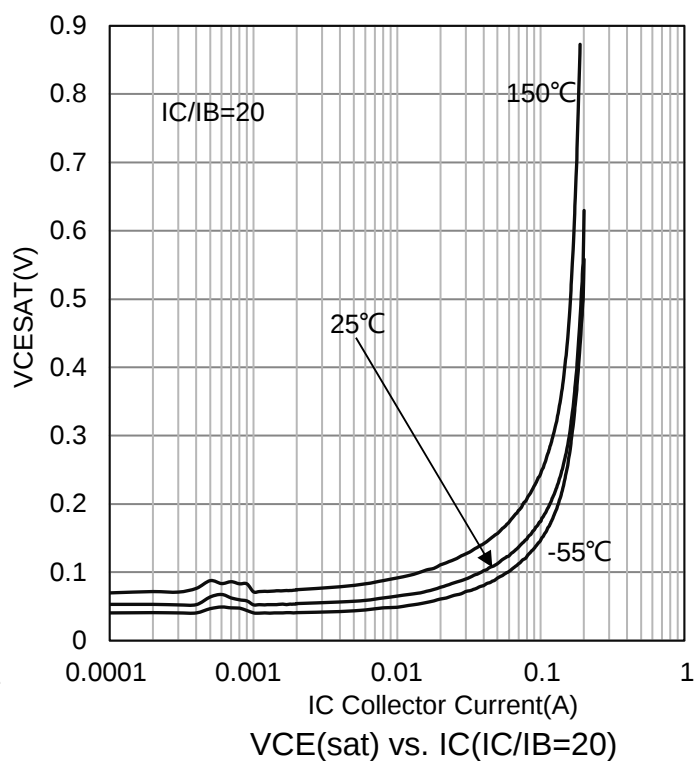
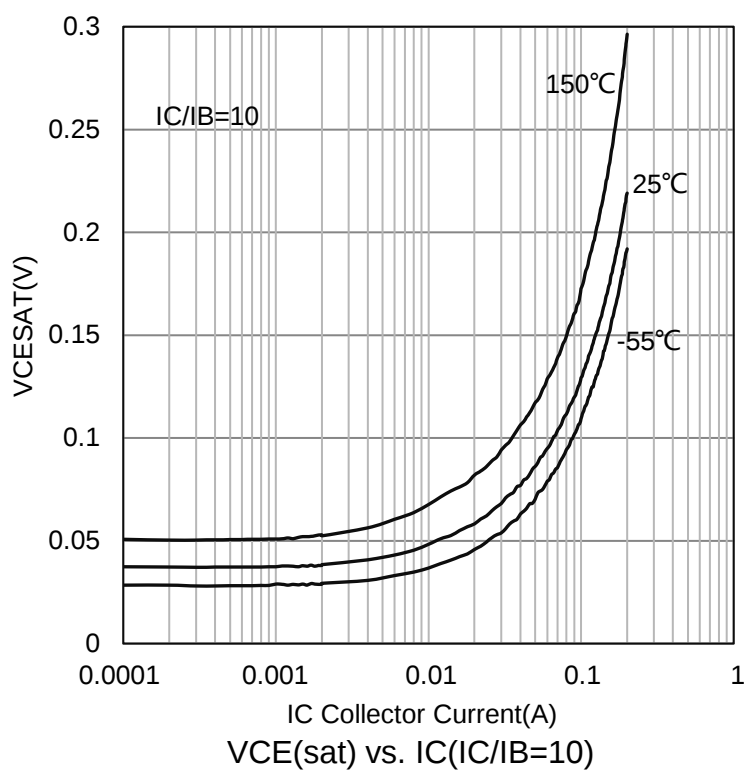
6.ELECTRICAL CHARACTERISTICS CURVES



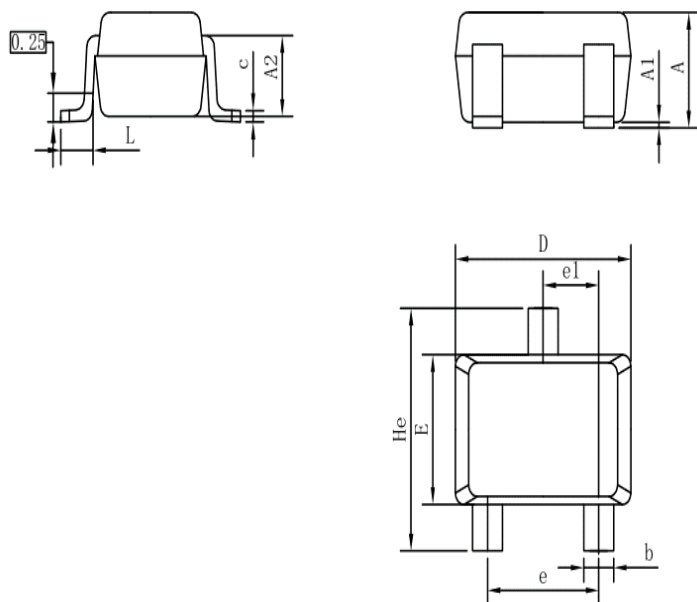
6.ELECTRICAL CHARACTERISTICS CURVES(Con.)



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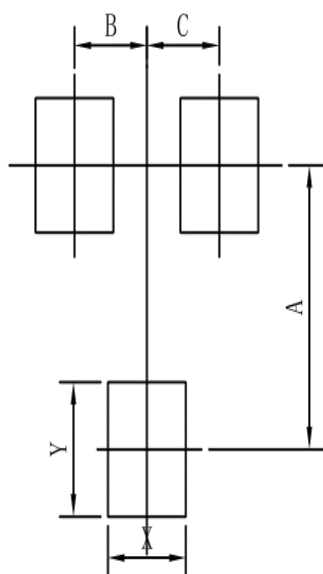


7.OUTLINE AND DIMENSIONS



SC70			
DIM	MIN	NOR	MAX
A	0.80	0.95	1.00
A1	0.00	0.05	0.10
A2	0.7 REF		
b	0.30	0.35	0.40
c	0.10	0.15	0.25
D	1.80	2.05	2.20
E	1.15	1.30	1.35
e	1.20	1.30	1.40
e1	0.65 BSC		
L	0.20	0.35	0.56
He	2.00	2.10	2.40
ALL Dimension in mm			

8.SOLDERING FOOTPRINT



SC70	
DIM	MIN
A	1.90
B	0.65
C	0.65
X	0.70
Y	0.90

DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.
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